

Power Transistor (-80V, -4A)

2SA2017

●Features

- 1) Low $V_{CE(sat)}$. (Typ. -0.3V at $I_C/I_B = -2 / -0.2A$)
- 2) Excellent DC current gain characteristics.
- 3) $P_c = 30W$ ($T_c = 25^\circ C$)
- 4) Wide SOA (safe operating area).
- 5) Complements the 2SC5574.

●Absolute maximum ratings ($T_a = 25^\circ C$)

| Parameter | Symbol | Limits | Unit |
|-----------------------------|-----------|----------|-------------------------|
| Collector-base voltage | V_{CBO} | -80 | V |
| Collector-emitter voltage | V_{CEO} | -80 | V |
| Emitter-base voltage | V_{EBO} | -5 | V |
| Collector current | I_C | -4 -6 | A A(Pulse) |
| Collector power dissipation | P_c | 30 | W($T_c = 25^\circ C$) |
| Junction temperature | T_j | 150 | °C |
| Storage temperature | T_{stg} | -55~+150 | °C |

●Packaging specifications and h_{FE}

| | |
|------------------------------|----------|
| Type | 2SA2017 |
| Package | TO-220FN |
| h_{FE} | E |
| Code | - |
| Basic ordering unit (pieces) | 500 |

●Electrical characteristics ($T_a = 25^\circ C$)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|--------------------------------------|---------------|------|------|------|---------|-------------------------------------|
| Collector-emitter breakdown voltage | BV_{CEO} | -80 | - | - | V | $I_C = -1mA$ |
| Collector-base breakdown voltage | BV_{CBO} | -80 | - | - | V | $I_C = -50\mu A$ |
| Emitter-base breakdown voltage | BV_{EBO} | -5 | - | - | V | $I_E = -50\mu A$ |
| Collector cutoff current | I_{CBO} | - | - | -10 | μA | $V_{CB} = -80V$ |
| Emitter cutoff current | I_{EBO} | - | - | -10 | μA | $V_{EB} = -4V$ |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | - | - | -1.5 | V | $I_C/I_B = -2A/-0.2A$ |
| Base-emitter saturation voltage | $V_{CE(sat)}$ | - | - | -1.5 | V | $I_C/I_B = -2A/-0.2A$ |
| DC current transfer ratio | h_{FE} | 100 | - | 200 | - | $V_{CE}/I_C = -4V/-1A$ |
| Transition frequency | f_T | - | 12 | - | MHz | $V_{CE} = -12V, I_E = 0.5A$ |
| Output capacitance | C_{ob} | - | 80 | - | pF | $V_{CB} = -10V, I_E = 0A, f = 1MHz$ |